NSN 5962-01-363-4986

Memory Microcircuit - Page 1 of 1



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| Operating Tempurature Range: |
|------------------------------------------------------------------------------------------------------------------------------------------|
| -55.0/+150.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| End Application: |
| An/gpn-22&tpn e/i fscm 49956 |
| Features Provided: |
| Programmed |
| Inclosure Material: |
| Ceramic |
| Inclosure Configuration: |
| Dual-in-line Dual-in-line |
| Output Logic Form: |
| Bipolar metal-oxide semiconductor |
| Case Outline Source And Designator: |
| D-9 mil-m-38510 |
| Terminal Surface Treatment: |
| Solder |
| Product Name: |
| Microcircuit digital fused pal |
| Voltage Rating And Type Per Characteristic: |
| -0.5 volts absolute input and 7.0 volts absolute input |
| Memory Device Type: |
| Pal |
| Test Data Document: |
| 49956-g504228 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; |
| excludes any specification, standard or other document that may be referenced in a basic governing drawing) |
| Terminal Type And Quantity: |
| 24 printed circuit |
| Specification Data: |
| 67268-5962-86053/tx/ government standard |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| Yes - demil/mli |
| Fiig: |
| A458a0 |
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